NSN 5962-01-352-1880

Memory Microcircuit - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5962-01-352-1880 **Body Length:** 1.290 inches **Body Width:** Between 0.220 inches and 0.310 inches **Body Height:** Between 0.150 inches and 0.210 inches **Operating Tempurature Range:** -55.0/+125.0 degrees celsius **Storage Tempurature Range:** -65.0/+150.0 degrees celsius **Features Provided:** Monolithic and programmable and burn in **Inclosure Material:** Ceramic **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Transistor-transistor logic **Input Circuit Pattern:** 19 input **Current Rating Per Characteristic:** 100.00 milliamperes reverse current, dc absolute **Terminal Surface Treatment:** Solder **Product Name:** And-or/and-or invert gate array Voltage Rating And Type Per Characteristic: 7.0 volts power source **Memory Device Type:** Pal **Terminal Type And Quantity:** 24 printed circuit Shelf Life: N/a **Unit Of Measure: Demilitarization:**

Yes - demil/mli

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